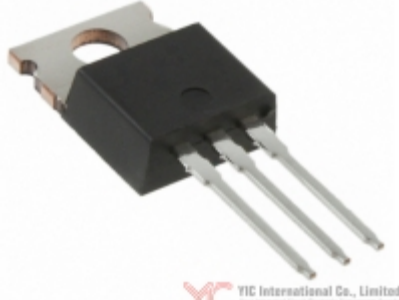
	<h2 style="color: red;">IRFBC40LCPBF</h2>
	<p><b>Hersteller-Teilenummer:</b> IRFBC40LCPBF</p> <p><b>Hersteller / Marke:</b> Vishay / Siliconix</p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 600V 6.2A TO-220AB</p> <p><b>Datenblätter:</b> <a href="#">1.IRFBC40LCPBF.pdf</a> <a href="#">2.IRFBC40LCPBF.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 5000 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	IRFBC40LCPBF
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 600V 6.2A TO-220AB
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	5000 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220AB
Verlustleistung (max)	125W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	6.2A (Tc)
Rds On (Max) @ Id, Vgs	1.2 Ohm @ 3.7A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	39nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1100pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube

IRFBC40LCPBF ist neu im Original, Suche IRFBC40LCPBF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IRFBC40LCPBF Vishay / Siliconix mit Garantie und Vertrauen. Anfrage IRFBC40LCPBF: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>IRFBC40LCL</b> Vishay / Siliconix MOSFET N-CH 600V 6.2A TO-262</p>	 <p><b>IRFBC40LCS</b> Vishay / Siliconix MOSFET N-CH 600V 6.2A D2PAK</p>	 <p><b>IRFBC40LCSTRL</b> Electro-Films (EFI) / Vishay MOSFET N-CH 600V 6.2A D2PAK</p>	 <p><b>IRFBC40LCL</b> Electro-Films (EFI) / Vishay MOSFET N-CH 600V 6.2A TO-262</p>
 <p><b>IRFBC40L</b> Vishay / Siliconix MOSFET N-CH 600V 6.2A TO-262</p>	 <p><b>IRFBC40LCSTRL</b> Vishay / Siliconix MOSFET N-CH 600V 6.2A D2PAK</p>	 <p><b>IRFBC40LC</b> Electro-Films (EFI) / Vishay MOSFET N-CH 600V 6.2A TO-220AB</p>	 <p><b>IRFBC40LCS</b> Electro-Films (EFI) / Vishay MOSFET N-CH 600V 6.2A D2PAK</p>

### heiße Teile

Mehr

⊗ IRFBC30LPBF	↔ IRFBC30LPBF	⇒ IRFBC30LTRR	D IRFBC30PBF	⇒ IRFBC30PBF
⊣ IRFBC30S	⊗ IRFBC30S	D IRFBC30STRLPBF	⇒ IRFBC30STRLPBF	⇒ IRFBC30STRR
⊗ IRFBC30STRR	⊣ IRFBC40A	⊗ IRFBC40A	↔ IRFBC40APBF	⇒ IRFBC40APBF
D IRFBC40AS	⊗ IRFBC40AS	⊣ IRFBC40ASPBF	⊗ IRFBC40ASPBF	⇒ IRFBC40ASTRRPBF
⇒ IRFBC40ASTRRPBF	↔ IRFBC40F	⊗ IRFBC40LC	⊣ IRFBC40LC	⇒ IRFBC40LCPBF
↔ IRFBC40LPBF	⇒ IRFBC40LPBF	D IRFBC40S	⊗ IRFBC40S	⊣ IRFBC40SPBF
⊗ IRFBC40SPBF	D IRFBC40STRL	⇒ IRFBC40STRL	↔ IRFBC40STRLPBF	⇒ IRFBC40STRLPBF
⊣ IRFBC40STRR	⊗ IRFBC40STRR	↔ IRFBC41LC	⇒ IRFBE20PBF	⇒ IRFBE20PBF
⊗ IRFBE20SPBF	⊣ IRFBE30L	⊗ IRFBE30L	D IRFBE30LPBF-M	⇒ IRFBE30PBF
↔ IRFBE30PBF	⊗ IRFBE30SPBF	⊣ IRFBE30SPBF	⊗ IRFBE30STRLPBF	⇒ IRFBE30STRLPBF

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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